

RESEARCH ARTICLE

View Article Online
View Journal | View IssueCite this: *Inorg. Chem. Front.*, 2023, **10**, 4425A unique $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ finite chain in oxychalcogenide $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ leading to ultra-low thermal conductivity and giant birefringence†Yong-Fang Shi,^{a,b} Sheng-Hua Zhou,^{a,b,c} Peng-Fei Liu,^d Xin-Tao Wu,^{a,b} Hua Lin^{*,a,b} and Qi-Long Zhu^{*,a,b}

Recently, heteroanionic materials have been drawing wide attention due to their unique crystal structures which result in fascinating physical properties. However, reports on structural exploration and functional application of lone-pair-cation-based oxychalcogenides are still very rare. In this work, a new Sb-based oxysulfide, $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$, was successfully obtained *via* a high-temperature solid-phase method. $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ belongs to the monoclinic space group of $P2_1/c$ (no. 14) and is formed by charge-balanced Ba^{2+} cations and zero-dimensional (0D) $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ finite chains made of the triangular-pyramid $[\text{SbOS}_2]$, quadrangular-pyramid $[\text{SbOS}_3]$ and teeter-totter $[\text{SbS}_4]$ units by sharing vertices. Note that the coexistence of various Sb-coordinated fashions in one material is surprisingly found for the first time. More encouragingly, such a unique 0D structure in $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ leads to an ultra-low thermal conductivity of $0.25 \text{ W m}^{-1} \text{ K}^{-1}$ at 700 K (one of the lowest values seen in a crystalline material) and a giant birefringence of 0.66 at 2050 nm (the highest value among metal chalcogenides reported thus far), which is further confirmed using theoretical calculations. As a result, this work will inspire intriguing and further research on heteroanionic materials with low-dimensional structures and hold great potential for their utilization in the photothermal field.

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Introduction

In recent years, low-dimensional inorganic chalcogenides with unique chemical bonding characteristics (ionic, covalent, or van der Waals) have attracted great attention because of their intriguing physical properties, such as photocatalysis, photoluminescence, magnetism, superconductivity, thermoelectricity, and second-order nonlinear optics (NLO).¹ For example, a remarkable photocurrent response was observed in the pentanary chalcogenide $\text{Rb}_2\text{Ba}_3\text{Cu}_2\text{Sb}_2\text{S}_{10}$, in which the structure is formed by one-dimensional (1D) $[\text{Cu}_2\text{Sb}_2\text{S}_{10}]^{8-}$ chains.² The quaternary sulphide $\text{Ba}_8\text{Zn}_4\text{Ga}_2\text{S}_{15}$ possesses a 1D

$[\text{Zn}_4\text{Ga}_2\text{S}_{15}]^{16-}$ chain structure and exhibits strong yellow photoluminescence emission at 298 K.³ An unprecedented two-dimensional (2D) layered chalcogenide $\text{Cs}_2[\text{Mn}_2\text{Ga}_3\text{S}_7\text{Cl}]$ displays distinguishing structural features with the coexistence of two Mn-based coordination geometries and exhibits an impressive ferrimagnetic phenomenon below 16 K.⁴ Two typical examples are the discovery of superconductivity in the ternary Bi-based tellurides CsBi_4Te_6 and $\text{RbBi}_{11/3}\text{Te}_6$, whose structures are made of alternately stacked 2D ionic $[\text{Bi}_4\text{Te}_6]^-$ and $[\text{Bi}_{11/3}\text{Te}_6]^-$ layers, respectively.⁵ Single-crystal SnSe exhibits a high figure of merit (ZT of 2.3 ± 0.3 at 973 K along the c axis) with an extremely low intrinsic thermal conductivity ($0.23 \pm 0.03 \text{ W m}^{-1} \text{ K}^{-1}$ at 973 K) owing to the unique wrinkled 2D layered structure.⁶ More recently, a quaternary non-centrosymmetric (NCS) material SrCdSi_4 , which features a 2D $[\text{CdSi}_4]^{2-}$ layered structure, was reported to exhibit superior IR-NLO comprehensive performances.⁷

In contrast to extensively reported layered 2D and 1D chain chalcogenides, reports on zero-dimensional (0D), *e.g.* “molecular”, inorganic chalcogenides are very scarce. On one hand, these 0D inorganic chalcogenides are mainly obtained through high-temperature solid-state methods. On the other hand, they have a simple structural composition and show a unique physical performance. For instance, the quaternary selenide

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Ba₂ASGaSe₅ shows a strong visible-light-induced photocatalytic performance (6.5 times larger than that of titanium dioxide powder (P25)), which can be attributed to the discrete novel [AsGaSe₅]⁴⁻ clusters.⁸ Strong second-harmonic generation (SHG) intensities were observed in the NCS chalcogenides Ba₂₃Ga₈Sb₂S₃₈ and M₂As₂Q₅ (M = Ba, Pb; Q = S, Se), in which the structure is composed of isolated [GaS₄] tetrahedra and [SbS₃] pyramids in the former and multiple discrete [As_xQ_y] anions in the latter.⁹ In the quaternary sulphide Ba₃HgGa₂S₇, the combination of seesaw-like [HgS₂] units and tetrahedral [GaS₄] groups prompts the formation of [Hg₂Ga₄S₁₄]¹²⁻ strings which could increase the polarizability of the crystal structure, thus a large birefringence (0.09@2100 nm) was achieved in this compound.¹⁰

Oxychalcogenides, which combine two different types of anions in one structure (*i.e.*, high electronegativity O²⁻ and

low electronegativity Q²⁻), have emerged as a new type of low-dimensional functional material in recent years.¹¹ Despite a great number of reports on novel oxychalcogenides with 1D and 2D structures so far, the exploration of 0D structures, especially for Sb-based oxychalcogenides, is quite limited. Hence, in this work, we take interest in the AE/Sb/O/Q (AE = alkaline-earth metal elements; Q = S, Se) system, hoping to obtain low-dimensional structures. Fortunately, a novel Sb-based oxychalcogenide Ba₆Sb₆O₂S₁₃ with a 0D structure was discovered in this quaternary family. Notably, the [Sb₆O₂S₁₃]¹²⁻ finite chain which is not normally found in inorganic chalcogenides is formed in this structure. Here, we report the solid-state synthesis, crystal structure, thermal transport and optical properties, as well as theoretical calculations of Ba₆Sb₆O₂S₁₃.

Results and discussion

Ba₆Sb₆O₂S₁₃ represents a new combination of the quaternary AE/Sb/O/Q (AE = alkaline-earth metals; Q = chalcogen) system and belongs to the monoclinic space group of *P2₁/c* (no. 14) [Pearson symbol: *mP54*; idealized Wyckoff sequence: *e*¹³*a*] (Table 1). Its asymmetric unit is made up of 6 Ba, 6 Sb, 2 O and 13 S atoms, which are all at the Wyckoff position of 4*e* except O1 and O2 at 2*a* (Table 2). As illustrated in Fig. 1a, the Sb1 atom is coordinated to the 1 O atom and 2 S atoms forming a trigonal planar [Sb1OS₂] basic building unit (BBU) while Sb3 atoms are surrounded by the 1 O atom and 3 S atoms in a distorted teeter-totter [Sb2OS₃] environment. The Sb2 atom shows a common teeter-totter coordination mode with 4 S atoms. It is worth mentioning that the coordination diversity of Sb atoms (*i.e.*, [SbOS₂], [SbOS₃], and [SbS₄]) in a single structure has been discovered for the first time. The Sb–O and Sb–S distances are 2.023–2.085 and 2.393–2.858 Å (Table S1†), respectively, which are comparable to those in the reported Sb-based chalcogenides.¹² The heteroanionic [Sb1OS₂] and [Sb3OS₃] BBUs adopt O-sharing and S4-sharing to form [Sb₂S₄O]⁴⁻ groups, which are further connected by isolated [SbS₄] units resulting in a unique finite [Sb₆O₂S₁₃]¹²⁻

Table 1 Crystallographic information and refinement results for Ba₆Sb₆O₂S₁₃

Empirical formula	Ba ₆ Sb ₆ O ₂ S ₁₃
CCDC number	2247687
Formula weight	2003.32
Temperature (K)	293(2)
Crystal size (mm)	0.15 × 0.10 × 0.10
Crystal system	Monoclinic
Space group	<i>P2₁/c</i> (no. 14)
<i>a</i> (Å)	8.7497(7)
<i>b</i> (Å)	14.2018(8)
<i>c</i> (Å)	11.7822(8)
α (°)	90
β (°)	96.616(5)
γ (°)	90
<i>V</i> (Å ³)	1454.3(2)
<i>Z</i>	2
<i>D_c</i> (g cm ⁻³)	4.575
μ (mm ⁻¹)	14.385
GOOF on <i>F</i> ²	1.052
<i>R</i> ₁ , <i>wR</i> ₂ (<i>I</i> > 2 σ (<i>I</i>)) ^a	0.0248, 0.0521
<i>R</i> ₁ , <i>wR</i> ₂ (all data)	0.0271, 0.0534
Largest diff. peak and hole (e Å ⁻³)	1.23, -2.03

$$^a R_1 = \sum ||F_o| - |F_c|| / \sum |F_o|, wR_2 = [\sum w(F_o^2 - F_c^2)^2 / \sum w(F_o^2)^2]^{1/2}.$$

Table 2 The atomic coordinates and equivalent isotropic displacement parameters for Ba₆Sb₆O₂S₁₃

Atom	Wyckff.	<i>x</i>	<i>y</i>	<i>z</i>	<i>U</i> _{eq} /Å ²	BVS
Ba1	4 <i>e</i>	0.29892(4)	0.13605(3)	0.09160(3)	0.00175(2)	1.96
Ba2	4 <i>e</i>	0.59957(4)	0.16259(3)	0.45656(3)	0.00153(2)	1.85
Ba3	4 <i>e</i>	0.90869(4)	0.36339(3)	0.28593(3)	0.00165(2)	1.96
Sb1	4 <i>e</i>	0.15729(5)	0.39552(3)	0.96110(4)	0.00142(2)	2.87
Sb2	4 <i>e</i>	0.80265(5)	0.11340(3)	0.11129(4)	0.00227(2)	3.25
Sb3	4 <i>e</i>	0.39253(6)	0.38288(4)	0.22091(4)	0.00293(2)	2.85
O	4 <i>e</i>	0.3381(5)	0.3300(3)	0.0620(4)	0.00150(9)	2.01
S1	4 <i>e</i>	1	0	0	0.00365(7)	1.91
S2	4 <i>e</i>	0.3268(2)	0.4891(2)	0.8539(2)	0.00163(3)	1.68
S3	4 <i>e</i>	0.2440(2)	0.2778(2)	0.3231(2)	0.00181(4)	1.93
S4	4 <i>e</i>	0.1412(2)	0.4986(2)	0.1287(2)	0.00217(4)	1.64
S5	4 <i>e</i>	0.9404(2)	0.2469(2)	0.0440(2)	0.00179(3)	1.91
S6	4 <i>e</i>	0.6129(2)	0.2376(2)	0.2100(2)	0.00267(4)	2.05
S7	4 <i>e</i>	0.6150(2)	0.0967(2)	0.9479(2)	0.00200(4)	1.91

*U*_{eq} is defined as one third of the trace of the orthogonalized *U*_{*ij*} tensor.

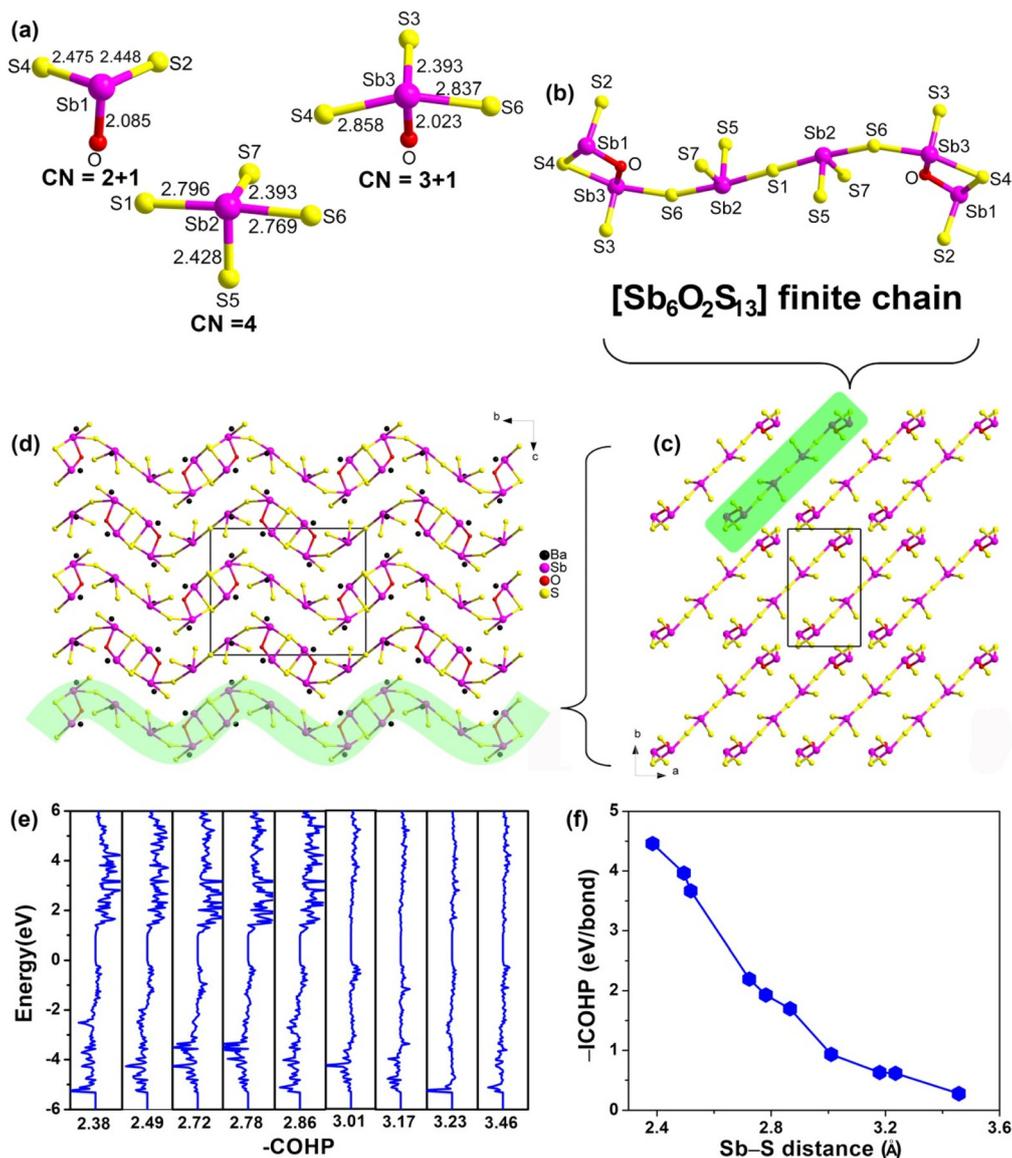


Fig. 1 (a) Coordination modes of $[\text{SbOS}_2]$, $[\text{SbOS}_3]$ and $[\text{SbS}_4]$ BBU; (b) coordination environment of the $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ finite chain with marked atom numbers; (c) distribution of OD finite chains on the ab plane; (d) ball-and-stick representation of the unique OD finite chain structure of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ viewed along the bc plane; (e) the COHP diagram for Sb-S bond distances; (f) ICOHP plotted against Sb-S bond distances.

chain (Fig. 1b). The specific distributions of these finite $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ chains parallel to the a - b plane and b - c plane are shown in Fig. 1c and d, respectively. The charge-balanced Ba^{2+} cations are distributed in the spaces of finite $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ chains, that possess two different coordination modes, *i.e.*, $[\text{BaS}_8]$ and $[\text{BaOS}_8]$ polyhedra, with Ba-S distances of 3.110–3.702 Å and Ba-O distances of 2.728–2.802 Å (Fig. S1 and Table S1†). The valence states of Ba, Sb, O, and S atoms are determined as 2+, 3+, 2-, and 2-, respectively, according to BVS calculations.¹³ Actually, there still exist 4 other Sb-S interactions with bond distances of 3.01–3.46 Å, which are much larger than the average Sb-S bond distance (2.65 Å) in the structure of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$. For this reason, the detailed COHP and ICOHP were applied to the in-depth study of the

interaction characteristics between Sb and S.¹⁴ As plotted in Fig. 1e and d, the results of the crystal orbital Hamiltonian population (COHP) and integrated COHP (ICOHP) analyses indicate that the bonding interactions of the short Sb-S bonds (2.38–2.86 Å) are much stronger than those of the long Sb-S bonds (3.01–3.46 Å), which supports the coordination environment of Sb atoms in the above-mentioned structural analysis.

It is very interesting to compare the above structures with the previously reported structures of $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$ ¹⁵ and $\text{Ba}_2\text{Sb}_2\text{O}_5$.¹⁶ From the perspective of structural chemistry, quaternary $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ and $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$ (denoted as $\text{Ba}_6\text{Sb}_6\text{O}_6\text{S}_9$) oxychalcogenides can be considered as derivatives by the partial chemical substitution approach (*i.e.*, partial O is replaced by S atoms) with ternary $\text{Ba}_2\text{Sb}_2\text{O}_5$ (denoted as

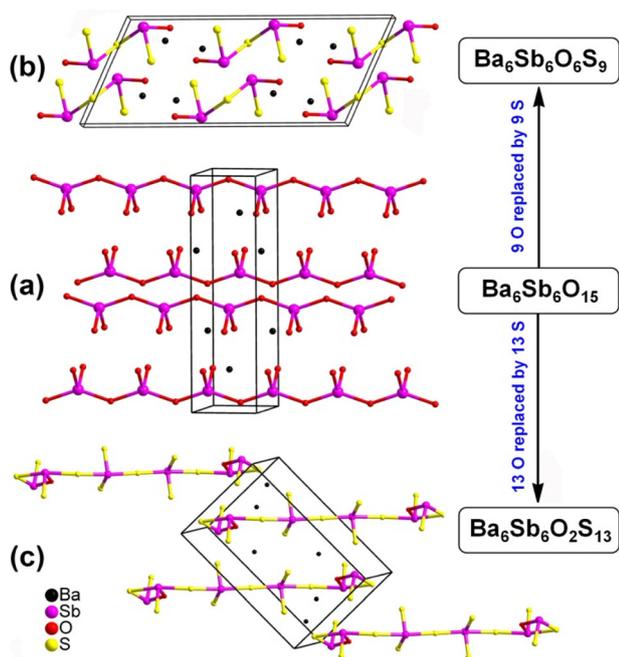


Fig. 2 Structural evolutions from (a) ternary $\text{Ba}_2\text{Sb}_2\text{O}_5$ (denoted as $\text{Ba}_6\text{Sb}_6\text{O}_{15}$) to quaternary oxychalcogenide (b) $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$ (denoted as $\text{Ba}_6\text{Sb}_6\text{O}_6\text{S}_9$) and (c) $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ by the partial chemical substitution approach.

$\text{Ba}_6\text{Sb}_6\text{O}_{15}$) as the structural template (see Fig. 2 for details). They have a similar molecular formula, but they exhibit some significantly different structural features: (i) $\text{Ba}_2\text{Sb}_2\text{O}_5$ is crystalline in the orthorhombic crystal system, whereas $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ and $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$ belong to the monoclinic crystal system; (ii) 1D infinite $[\text{Sb}_2\text{O}_5]^{4-}$ chains are isolated in $\text{Ba}_2\text{Sb}_2\text{O}_5$, whereas 0D finite $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ chains and isolated $[\text{Sb}_2\text{O}_2\text{S}_3]^{4-}$ clusters are found in $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ and $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$, respectively; (iii) compounds $\text{Ba}_2\text{Sb}_2\text{O}_5$ and $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$ possess only one type of Sb-based BBU, *i.e.*, $[\text{SbO}_4]$ and $[\text{SbO}_2\text{S}]$, while $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ shows three different kinds of BBUs, *i.e.*, $[\text{SbOS}_2]$, $[\text{SbOS}_3]$, and $[\text{SbS}_4]$. Fig. 2 clearly shows the detailed structural evolution from the $\text{Ba}_2\text{Sb}_2\text{O}_5$ prototype to the derived $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$ and $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$. In brief, these findings not only enrich the structural library of heteroanionic compounds but also provide a new approach for designing and exploring new low dimensional oxychalcogenides.

Furthermore, the properties of the title compound together with other previously reported Sb-based oxychalcogenides are briefly analysed, concluded and summarized (see Table S2† for details).^{12b,15,17} From the perspective of structural chemistry, their composition can generally be divided into two parts: charge-balanced cations and anionic substructure. The former is mainly composed of alkaline-earth metals (*e.g.*, Ca, Sr, and Ba) as well as a small amount of rare earth elements (*e.g.*, La and Ce) and Pb, while the latter shows diversity in structural dimensions. Structural analysis shows that there are two main types of BBUs for Sb atoms with stereochemically-active-lone-

pairs (SCALPs) in the anionic substructure, *i.e.*, monoanionic $[\text{SbO}_n]/[\text{SbQ}_n]$ ($n = 3, 4,$ and 5) and heteroanionic $[\text{SbO}_x\text{Q}_y]$ ($x + y = 3, 4,$ and 5) BBUs. Then, these Sb-based BBUs are further connected to each other or other metal-based BBUs to generate 0D molecules, 1D chains, 2D layers, 3D networks or mixed-dimensional structures. As given in Table S2,† all these oxychalcogenides possess high S-to-O ratios and crystallize in low symmetry monoclinic space groups, except for orthorhombic $\text{La}_6\text{Sb}_4\text{O}_{12}\text{S}_3$. Moreover, most of them have a 2D layered structure (*ca.* 40%). Usually, low-dimensional chalcogenides can be obtained by enhancing the proportion of charge-balanced cations according to the viewpoint of “dimensional reduction”.¹⁸ Actually, this structural law is not followed in this quaternary family, for instance, $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$, $\text{Sr}_2\text{Sb}_2\text{O}_2\text{Se}_3$, and $\text{Sr}_{3.5}\text{Pb}_{2.5}\text{Sb}_6\text{O}_5\text{Se}_{10}$, have the same $[\text{X}/\text{Sb}]$ ratio of 1.0, but their corresponding structural dimensions are 0D, 1D, and 2D, respectively. Similar phenomena can also be observed in other SCALP-based chalcogenide systems.¹⁹

Single crystals of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ were obtained by high temperature solid-state reactions of a mixture of BaS, Sb_2O_3 and Sb_2S_3 at 973 K (see the Experimental section in the ESI†). The elemental distributions of Ba : Sb : O : S were determined by EDX mapping as 6 : 6 : 2 : 13 (Fig. 3a and S2†), which are consistent with the results of single-crystal XRD analysis. The experimental powder XRD patterns matched with the simulated ones very well (Fig. 3b), without other impurities being present. UV-Vis-NIR diffuse reflectance spectroscopy was carried out to investigate the optical absorption properties of the title compound. As presented in Fig. 3c, the deduced optical E_g value of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ is 1.68 eV, which is obviously smaller than that of the previously reported $\text{Ba}_2\text{Sb}_2\text{O}_2\text{S}_3$ (2.78 eV). Such significant change in the E_g value can be attributed to different O-to-S ratios, that is, the more O atoms are replaced by S atoms, the smaller E_g value is obtained. Moreover, TG and DSC measurements under a N_2 atmosphere indicate that $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ exhibits no obvious weight loss in the range of 300–1123 K. In addition, the DSC data show only one obvious endothermic peak at around 1017 K in the heating curve and one obvious exothermic peak at 953 K in the cooling curve, which illustrates $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ is a congruently melting compound (Fig. 3d).

In addition, inspired by a recent study that metal chalcogenides containing SCALPs exhibit extremely low intrinsic thermal conductivities,²⁰ we investigated the thermal transmission performance of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$. As shown in Fig. 4a, the total thermal conductivity (κ_T) of the polycrystalline $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ sample was measured in the temperature range of 303 to 723 K. It can be clearly seen that the κ_T value of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ gradually decreases to an ultra-low value from $\sim 0.38 \text{ W m}^{-1} \text{ K}^{-1}$ (at 303 K) to $\sim 0.25 \text{ W m}^{-1} \text{ K}^{-1}$ (at 723 K) on heating the sample. As is known, the κ_T value is the summation of lattice thermal conductivity (κ_L) and electrical thermal conductivity (κ_E) values.²¹ Since the E_g value of the title compound is large compared with that of classical thermoelectric materials, κ_E can be ignored, which means that the κ_T value of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ can be considered as κ_L .²² Moreover,

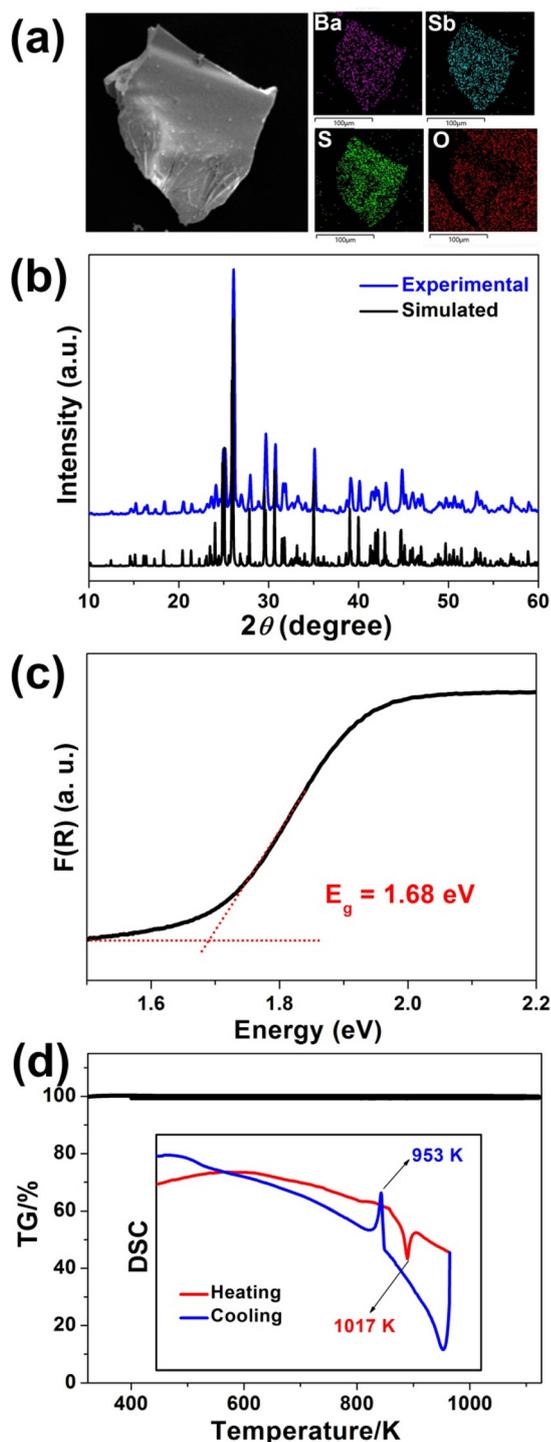


Fig. 3 Experimental characterization of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$: (a) the SEM image and the corresponding elemental mapping analysis; (b) experimental (blue) and simulated (black) PXRD patterns; (c) the solid-state diffuse reflectance spectrum; (d) TG diagram (inset: DSC cyclic curves).

the calculated minimum lattice thermal conductivity (κ_{min}) of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ was estimated using Cahill's model at about $0.27 \text{ W m}^{-1} \text{ K}^{-1}$.²³ The reason for $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ possessing an ultra-low κ_{L} value can be mainly attributed to the following two

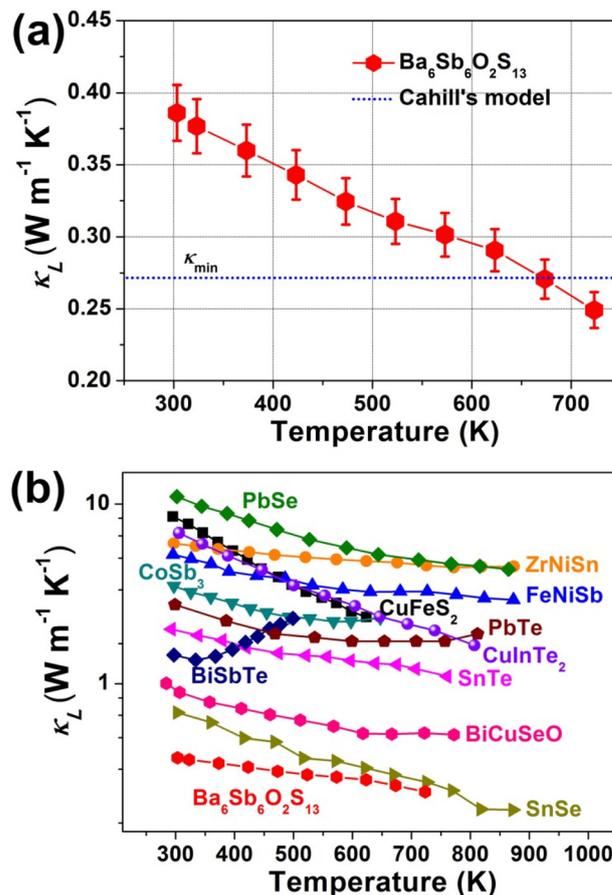


Fig. 4 (a) Lattice thermal conductivity (κ_{L}) as a function of temperature for $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ (the dashed line represents the minimum κ_{L} value calculated within the Cahill model) and (b) comparison of κ_{L} with other reported state-of-the-art thermoelectric materials.

aspects: (i) strongly ionic Ba^{2+} cations can decrease the phonon velocity and boost the phonon scattering ratio, and similar examples can also be found in other Ba-based systems;²⁴ (ii) due to the coexistence of multiple BBUs, the highly polarized $[\text{SbOS}_2]$ triangular pyramid, $[\text{SbOS}_3]$, and the $[\text{SbS}_4]$ square pyramid can effectively enhance the lattice anharmonicity.²⁵ Therefore, the low κ_{L} value for $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ was verified through experimental measurement and theoretical estimation. Fig. 4b shows the temperature dependence of the κ_{L} value of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ as well as those of some classical thermoelectric materials, including PbSe ($\sim 10.9\text{--}4.3 \text{ W m}^{-1} \text{ K}^{-1}$),²⁶ CuFeS_2 ($\sim 8.5\text{--}2.3 \text{ W m}^{-1} \text{ K}^{-1}$),²⁷ CuInTe_2 ($\sim 6.9\text{--}1.7 \text{ W m}^{-1} \text{ K}^{-1}$),²⁸ ZrNiSn ($\sim 6.1\text{--}4.5 \text{ W m}^{-1} \text{ K}^{-1}$),²⁹ FeNiSb ($\sim 5.2\text{--}3.0 \text{ W m}^{-1} \text{ K}^{-1}$),³⁰ CoSb_3 ($\sim 3.6\text{--}2.3 \text{ W m}^{-1} \text{ K}^{-1}$),³¹ PbTe ($\sim 2.8\text{--}1.9 \text{ W m}^{-1} \text{ K}^{-1}$),³² SnTe ($\sim 2.0\text{--}1.1 \text{ W m}^{-1} \text{ K}^{-1}$),³³ BiSbTe ($\sim 2.3\text{--}1.5 \text{ W m}^{-1} \text{ K}^{-1}$),³⁴ BiCuSeO ($\sim 1.0\text{--}0.5 \text{ W m}^{-1} \text{ K}^{-1}$)³⁵ and SnSe ($\sim 0.7\text{--}0.2 \text{ W m}^{-1} \text{ K}^{-1}$)³⁶ for comparison.

To gain further insight into the relationship between the crystal structure and optical properties, theoretical investigations based on the density functional theory (DFT) were performed on $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$. The electronic band structure along

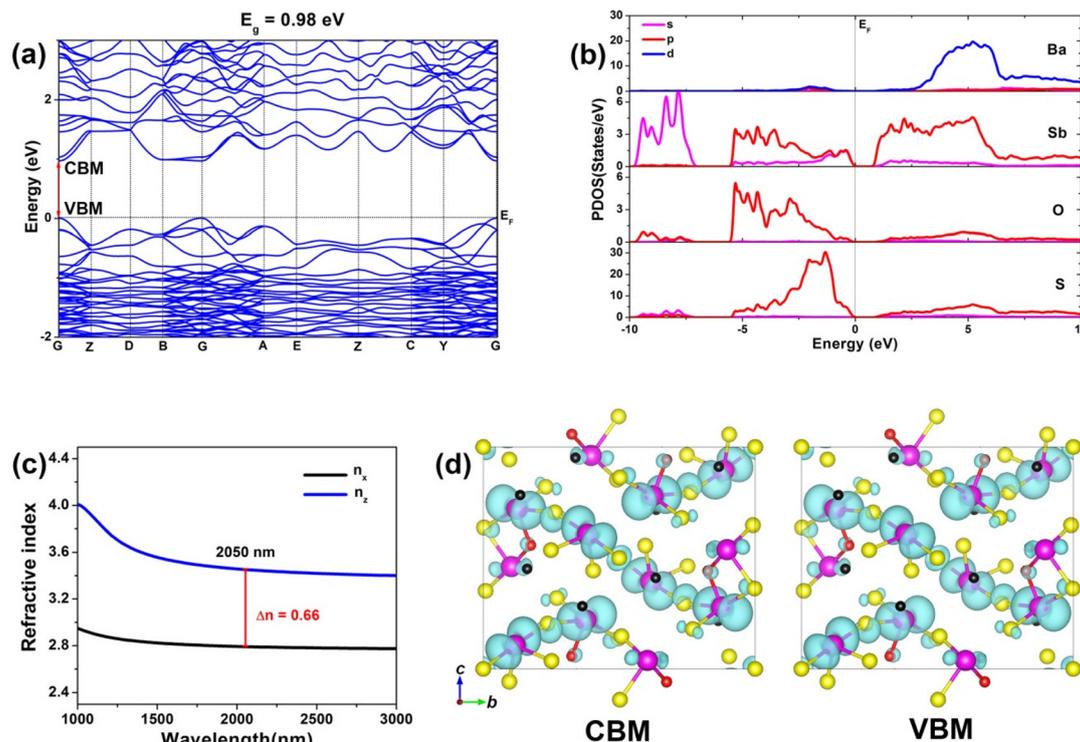


Fig. 5 Theoretical calculated results of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$: (a) calculated band structure; (b) PDOSs; (c) calculated birefringence (Δn); (d) projection of the charge density maps with major contributions in the CBM and VBM sections. Black atoms: Ba; pink atoms: Sb; red atoms: O; yellow atoms: S.

high symmetry points of the first Brillouin zone is plotted as shown in Fig. 5a and $\text{S3}, \uparrow$ which reveals that $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ is a direct band-gap semiconductor with an E_g value of 0.98 eV at the G-point. Although this value is smaller than the experimentally obtained value of 1.68 eV, standard exchange–correlation functionals in DFT are well-known for underestimating E_g .³⁷ As shown by the partial density of states (PDOS) in Fig. 5b, O-2p S-3p and Sb-5s/5p states provide dominant contributions to the top of the valence band (VB), while the bottom of the conduction band (CB) of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ is mainly constituted by S-3p and Sb-5p states, with little contributions from the O-2p and Ba-4d states. It can be concluded that the E_g of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ is determined by $[\text{SbOS}_2]$, $[\text{SbOS}_3]$, and $[\text{SbS}_4]$ BBUs, that is, 0D finite $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ chains.

It is generally believed that a large anisotropy of low dimensional structures is beneficial for obtaining a larger Δn value.³⁸ Given that, also the refractive index was recorded and charge density maps were plotted to offer a more intuitive understanding of the structure–activity relationship. As displayed in Fig. 5c, $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ exhibits a huge Δn value throughout the entire calculation range. Among them, the calculated Δn value is 0.66@2050 nm, greater than those of recently reported low-dimensional chalcogenides with SCALPs, such as RbBiP_2S_6 ($\Delta n_{(\text{cal.})} = 0.061@2050 \text{ nm}$),³⁹ $\text{K}_2\text{Ag}_3\text{Sb}_3\text{S}_7$ ($\Delta n_{(\text{cal.})} = 0.165@2050 \text{ nm}$),⁴⁰ $\text{Ba}_2\text{As}_2\text{Se}_5$ ($\Delta n_{(\text{cal.})} = 0.249@2050 \text{ nm}$),^{9b} CsZnAsSe_3 ($\Delta n_{(\text{cal.})} = 0.301@2050 \text{ nm}$),⁴¹ and $\text{CsCu}_3\text{SbS}_4$ ($\Delta n_{(\text{cal.})} = 0.442@2050 \text{ nm}$),⁴² which indicates that $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$

can be a promising IR birefringent candidate. Additionally, the experimental results also confirmed that the title compound has a wide IR transmission range from 0.75 to 18.3 μm (Fig. S4[†]). Furthermore, the calculation results based on the visual charge density maps (Fig. 5d) and electron localization function diagram (Fig. S5[†]) indicate that the synergistic effect of SCALP-based $[\text{SbOS}_2]$, $[\text{SbOS}_3]$, and $[\text{SbS}_4]$ BBUs in the 0D finite $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ chains of $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ is the core contribution for obtaining a giant Δn value.

Conclusions

In summary, a novel quaternary Sb-based oxychalcogenide, $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$, has been successfully obtained by a conventional solid-state method at 973 K. The discrete $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ finite chain, formed by triangular-pyramid $[\text{SbOS}_2]$, quadrangular-pyramid $[\text{SbOS}_3]$ and teeter-totter $[\text{SbS}_4]$ units, is observed for the first time. UV-Vis-NIR spectroscopy measurement shows that $\text{Ba}_6\text{Sb}_6\text{O}_2\text{S}_{13}$ possesses an optical E_g value of 1.68 eV. Benefiting from the ordered arrangement of 0D $[\text{Sb}_6\text{O}_2\text{S}_{13}]^{12-}$ finite chains, the title compound exhibits an ultra-low thermal conductivity ($0.25 \text{ W m}^{-1} \text{ K}^{-1}$ at 700 K) and an ultra-high birefringence (0.66 at 2050 nm). This work offers some new insights on Sb-based heteroanionic materials which would stimulate more exploratory syntheses and further enrich functional oxychalcogenides.

Author contributions

Y.-F. Shi prepared the samples, designed and carried out the experiments. S. H. Zhou and P. F. Liu carried out the theoretical calculations. X.-T. Wu provided discussion on the structure–property relationship of the title compound. H. Lin and Q.-L. Zhu conceived the experiments, analyzed the results and wrote and edited the manuscript. All the authors have approved the final version of the manuscript.

Conflicts of interest

There are no conflicts to declare.

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